NSN 5961-01-011-2086

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View Online at https://aerobasegroup.com/nsn/5961-01-011-2086 **Inclosure Material:** Ceramic and metal **Overall Length:** Between 0.790 inches and 0.810 inches **Overall Height:** Between 0.149 inches and 0.187 inches **Overall Width:** 0.740 inches **Mounting Facility Quantity: Electrode Internally-electrically Connected To Case:** Base **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 50.0 collector to base voltage/static/emitter open and 50.0 collector-to-emitter substaining voltage, resistance between base and emitter and 3.5 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 0.25 amperes source cutoff current **Power Rating Per Characteristic:** 5.8 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Terminal Type And Quantity:** 2 ribbon and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: